

EECS 151/251A

Spring 2021

Digital Design and Integrated Circuits

Instructor:
John Wawrzynek

Lecture 11: Timing Part 1

Announcements

- ❑ Virtual Front Row for today 2/23:
 - ❑ Ellie Wang
 - ❑ Jose Rodriguez
 - ❑ Jiefeng Chen
 - ❑ Rajiv Govindjee
 - ❑ James Shi
- ❑ **Questions/comments used in class participation points.**
- ❑ Homework assignment 5 posted - due Monday. Start early, challenging!

What do ASIC/FPGA Designers need to know about physics?

► Physics effect:

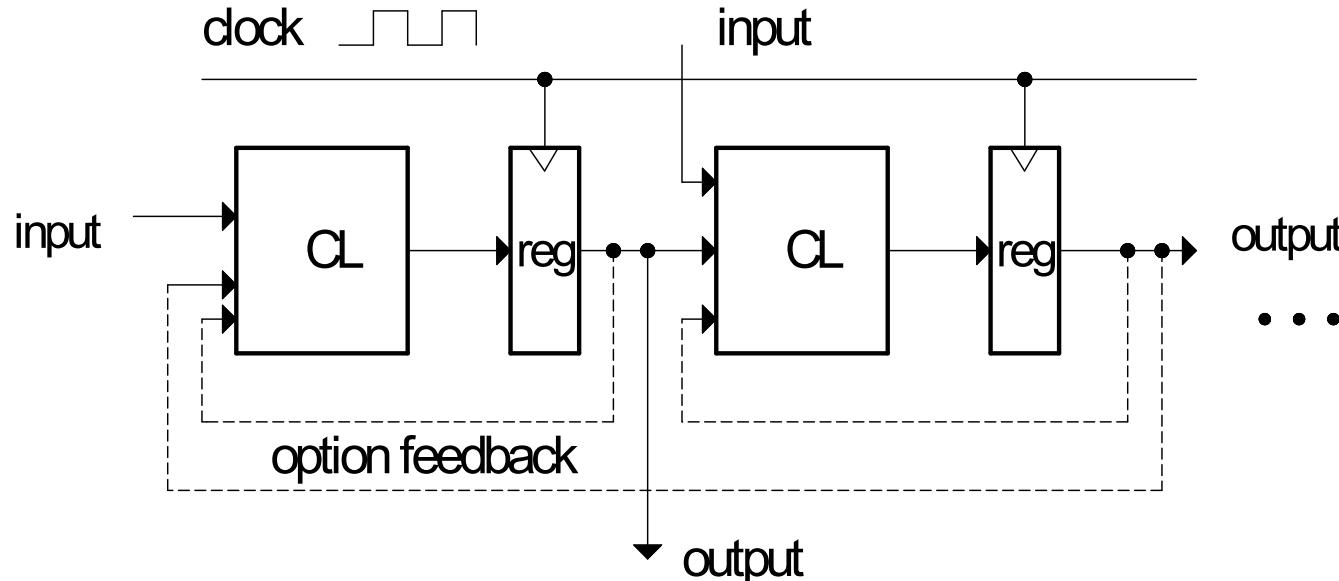
Area \Rightarrow cost

Delay \Rightarrow performance

Energy \Rightarrow performance & cost

- Ideally, zero delay, area, and energy. However, the physical devices occupy area, take time, and consume energy.
- CMOS process lets us build transistors, wires, connections, and we get capacitors, inductors, and resistors whether or not we want them.

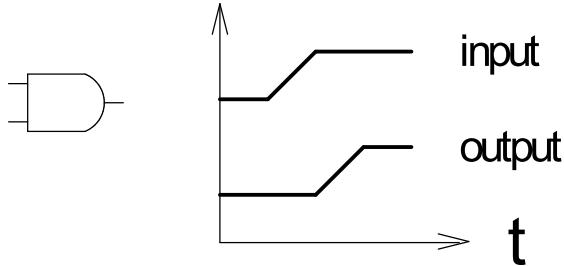
Performance, Cost, Power



- How do we measure performance?
operations/sec? cycles/sec?
- Performance is directly proportional to clock frequency. Although it may not be the entire story:
Ex: CPU performance
 $= \# \text{ instructions} \times \text{CPI} \times \text{clock period}$

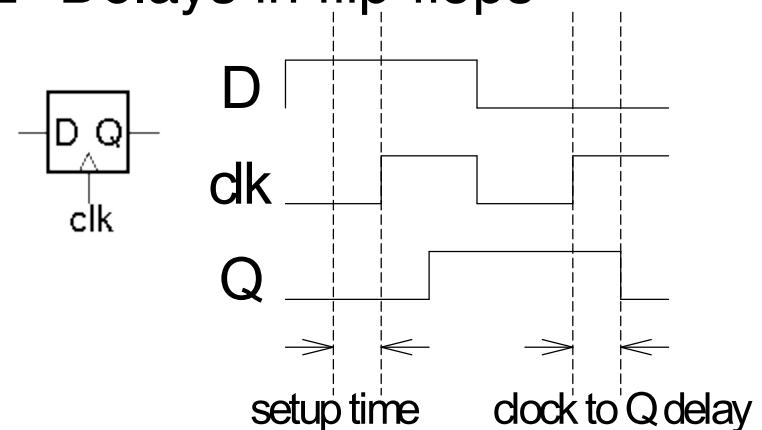
Limitations on Clock Rate

1 Logic Gate Delay



What are typical delay values?

2 Delays in flip-flops

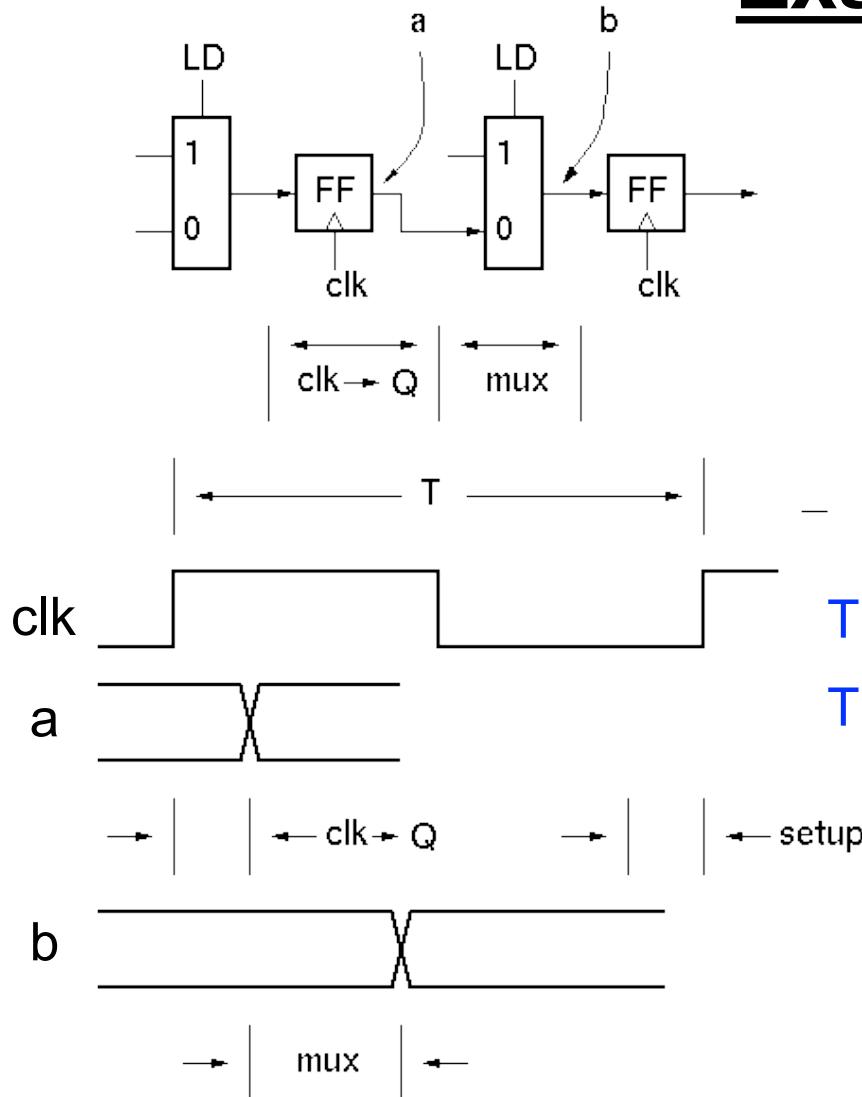


Both times contribute to limiting the clock period.

- What must happen in one clock cycle for correct operation?
 - All signals connected to FF (or memory) inputs must be ready and “setup” before rising edge of clock.
 - For now we assume perfect clock distribution (all flip-flops see the clock at the same time).

Example

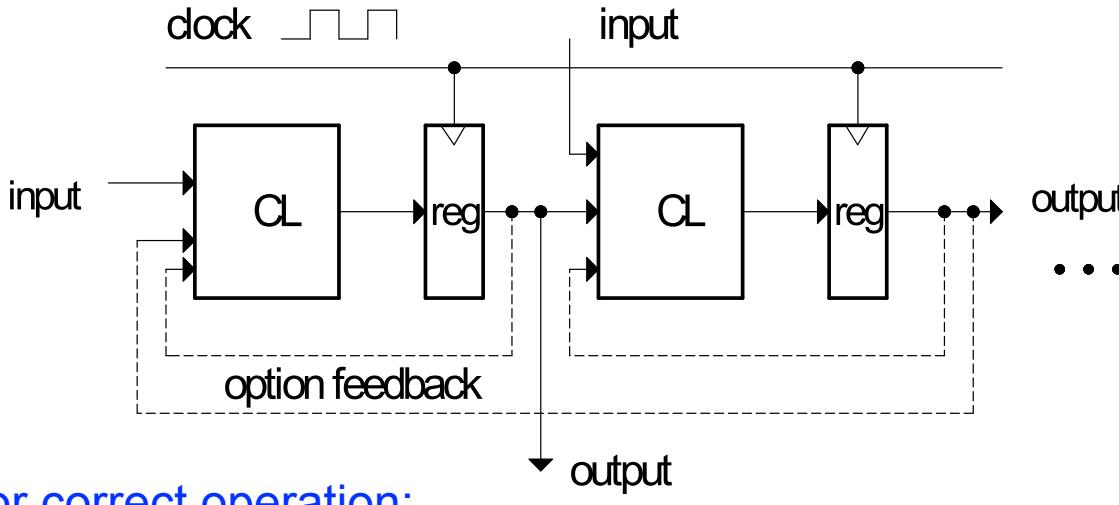
Parallel to serial
converter circuit



$$T \geq \text{time}(\text{clk} \rightarrow Q) + \text{time}(\text{mux}) + \text{time}(\text{setup})$$

$$T \geq \tau_{\text{clk} \rightarrow Q} + \tau_{\text{mux}} + \tau_{\text{setup}}$$

In General ...

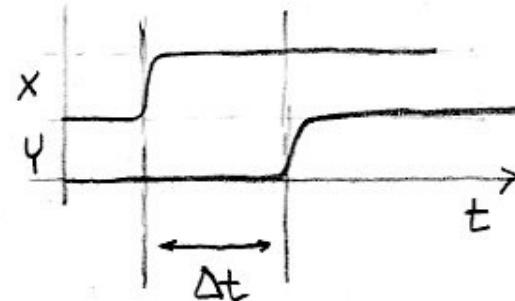
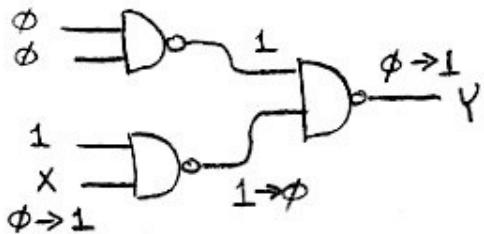


$$T \geq \tau_{\text{clk} \rightarrow Q} + \tau_{\text{CL}} + \tau_{\text{setup}}$$

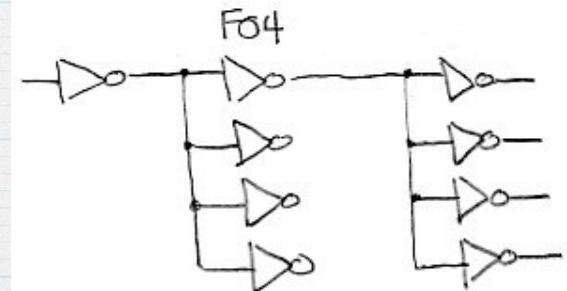
for all paths.

- How do we enumerate *all* paths?
 - Any circuit input or register output to any register input or circuit output?
- Note:
 - “setup time” for outputs is a function of what it connects to.
 - “clk-to-q” for circuit inputs depends on from where it comes.

“Gate Delay”



- ▶ Modern CMOS gate delays on the order of a few picoseconds. (However, highly dependent on gate design and context.)
- ▶ Often expressed as F04 delays (fan-out of 4) - as a process dependent delay metric:
 - ▶ the delay of an inverter, driven by an inverter 4x smaller than itself, and driving an inverter 4x larger than itself.
 - ▶ Less than 10ps for a 32nm process. For a 7nm process F04 is around 2.5ps.



Process Dependent FO4 Delay

Scaling equations for the accurate prediction of CMOS device performance from 180 nm to 7 nm

Aaron Stillmaker^{a,b,*}, Bevan Baas^a

^a Department of Electrical and Computer Engineering, University of California, Davis, One Shields Ave., Davis, CA 95616, USA

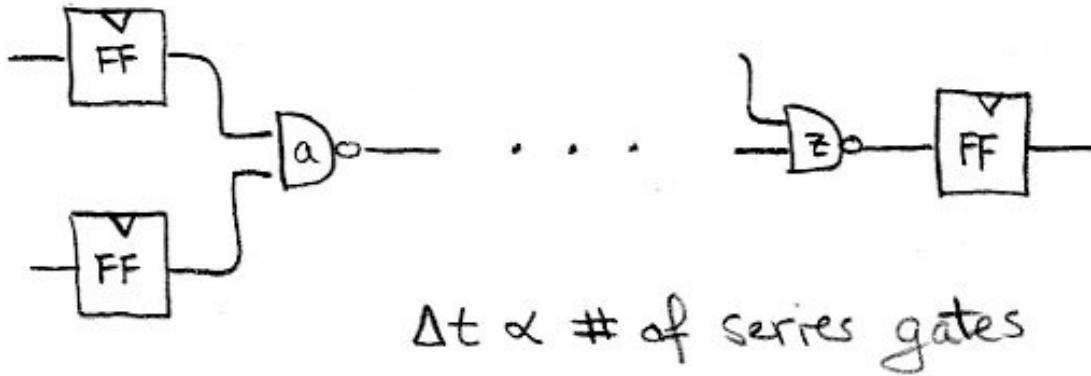
^b Department of Electrical and Computer Engineering, California State University, Fresno, 2320 E. San Ramon Ave., Fresno, CA 93740, USA

Characteristics of different technology nodes [23]. The modeled measurements are for a single inverter in an FO4 chain. The energy value is the average energy required for a single inverter transition from low to high, or high to low.

Production Year	Technology Node (nm)	Technology Type	V _{DD} (V)	Simulated Performance of Inverter		
				Delay (ps)	Energy (fJ)	Power (μW)
1999	180	Bulk	1.8	77.2	27.5	105
2001	130	Bulk	1.2	34.7	5.20	26.1
2004	90	Bulk	1.1	26.5	2.62	13.0
2007	65	Bulk	1.1	19.8	1.72	8.58
2008	45	High-k	1.1	10.9	1.05	5.19
2010	32	High-k	0.97	9.8	0.51	2.47
2012	20	Multi-Gate	0.9	9.66	0.198	1.51
2013	16 ^a	Multi-Gate	0.86	6.12	0.179	1.28
2013	14 ^a	Multi-Gate	0.86	4.02	0.144	0.995
2015	10	Multi-Gate	0.83	3.24	0.122	0.866
2017	7	Multi-Gate	0.8	2.47	0.111	0.789

^a The 2013 ITRS report labels a single "16/14" node.

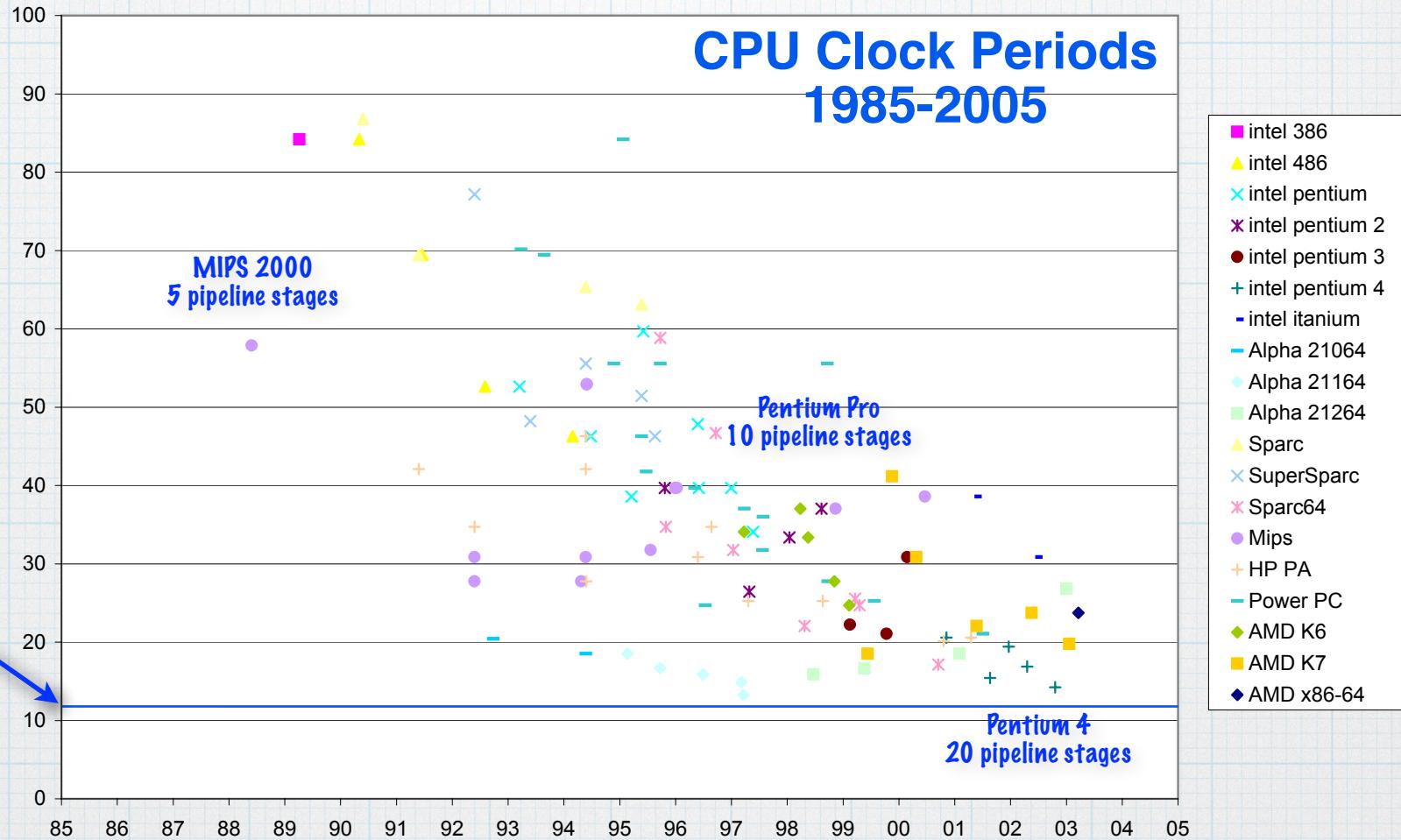
“Path Delay”



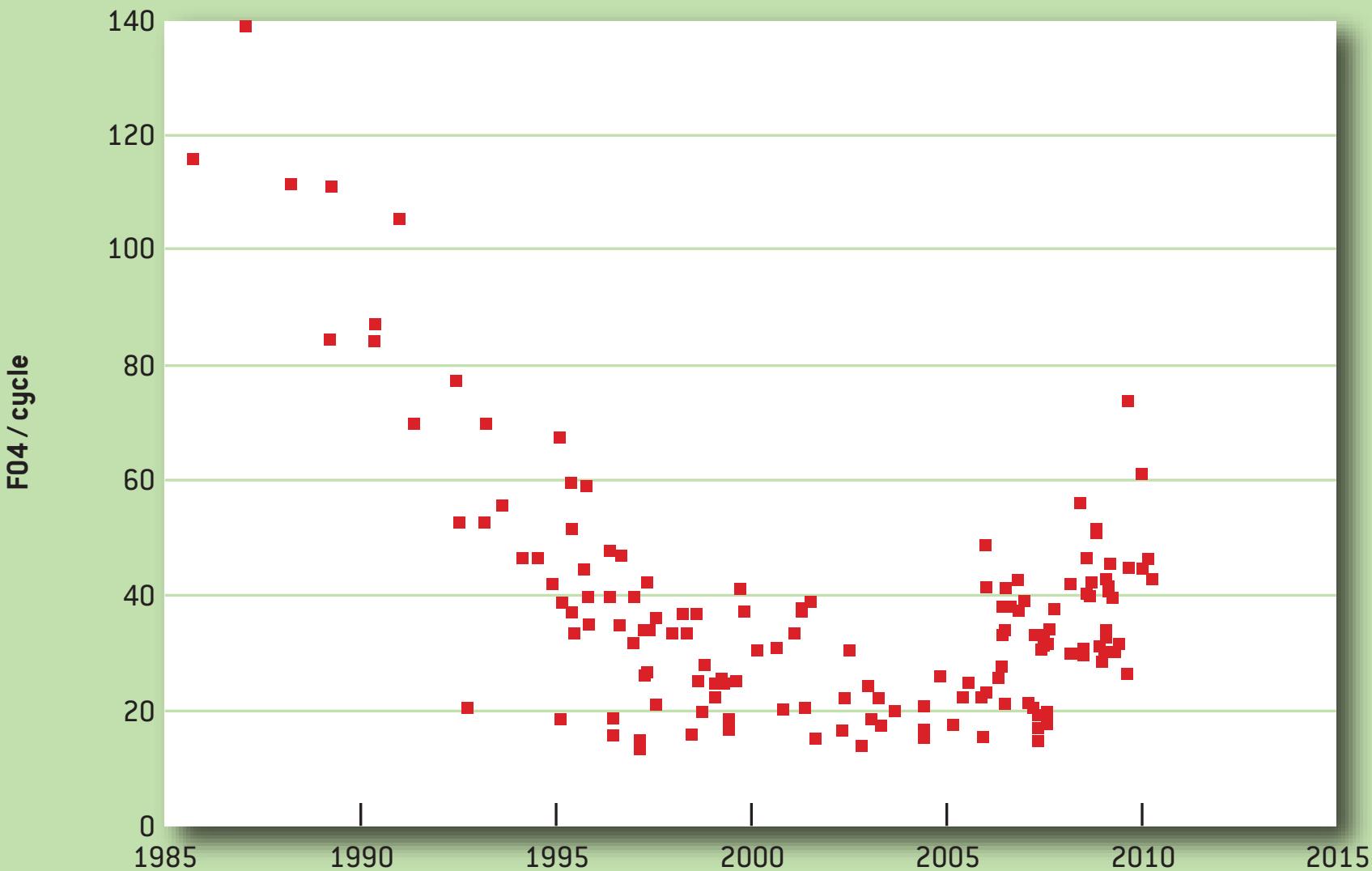
- ▶ For correct operation:
 $\text{Total Delay} \leq \text{clock_period} - \text{FF}_{\text{setup_time}} - \text{FF}_{\text{clk_to_q}}$
on all paths.
- ▶ High-speed processors critical paths (worst case paths) have around 20 F04 delays.

F04 Delays per clock period

F04
Delays



F04 Delays Per Cycle for Processor Designs

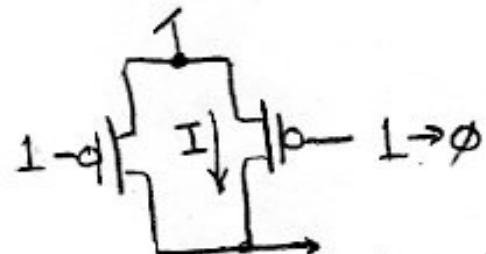


F04 delay per cycle is roughly proportional to the amount of computation completed per cycle.

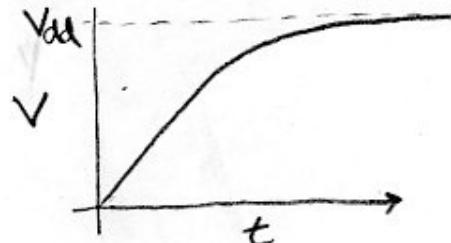
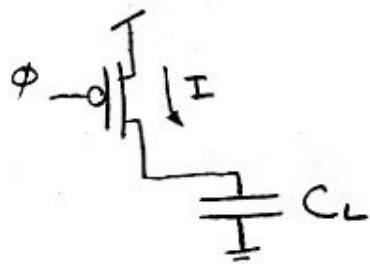
“Gate Delay”

- ▶ What determines the actual delay of a logic gate?
- ▶ Transistors are not perfect switches - cannot change terminal voltages instantaneously.
- ▶ Consider the NAND gate:

$$\begin{matrix} 1 \\ \downarrow \rightarrow \phi \end{matrix} \rightarrow \text{NAND} \rightarrow \begin{matrix} \phi \rightarrow 1 \\ 1 \rightarrow \phi \end{matrix}$$



- ▶ Current (I) value depends on: process parameters, transistor size

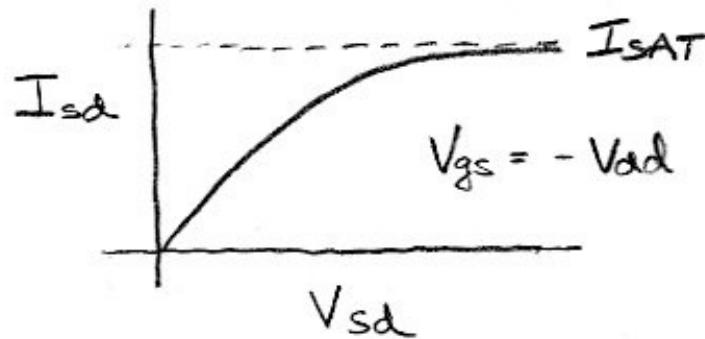
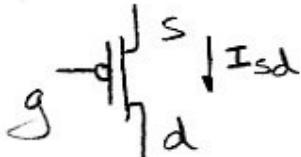


$$\Delta t \propto C_L / I$$

- ▶ C_L models gate output, wire, inputs to next stage (Cap. of Load)
- ▶ C “integrates” I creating a voltage change at output

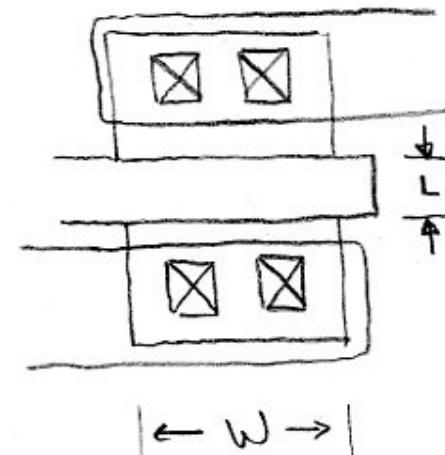
More on transistor Current

- ▶ Transistors actually act like a cross between a resistor and "current source"

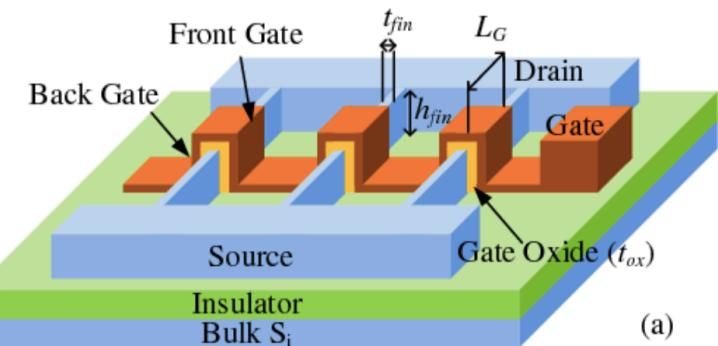


- ▶ I_{SAT} depends on process parameters (higher for nFETs than for pFETs) and transistor size (layout):

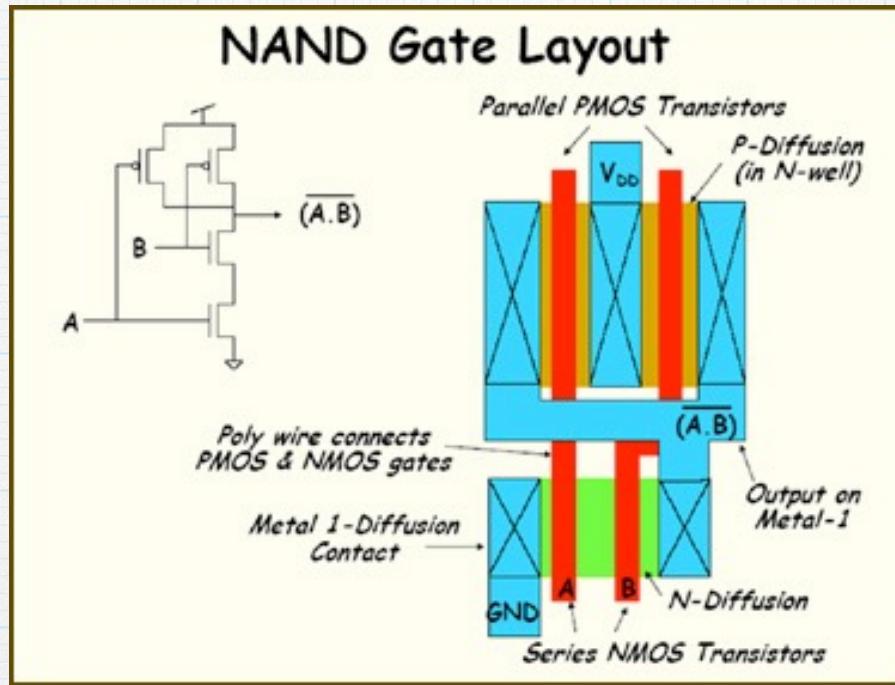
$$I_{SAT} \propto W/L$$



FinFets use multiple "fins" to get wider



Physical Layout determines FET strength

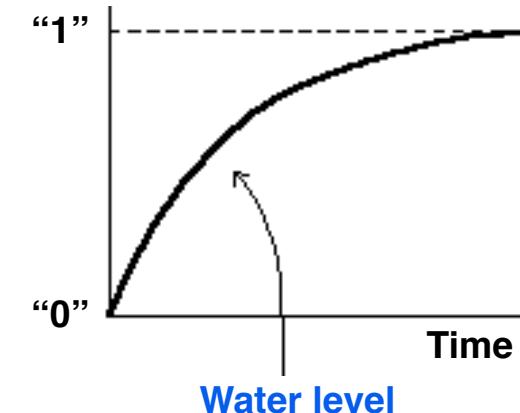
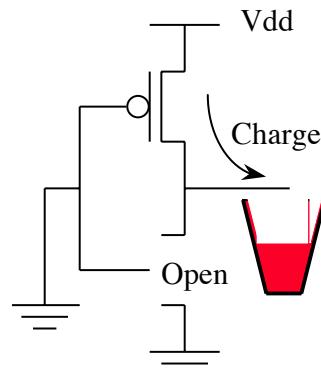


- ▶ “Switch-level” abstraction gives a good way to understand the function of a circuit.
 - ▶ nFET ($g=1$? short circuit : open)
 - ▶ pFET ($g=0$? short circuit : open)
- ▶ Understanding delay means going below the switch-level abstraction to transistor physics and layout details.

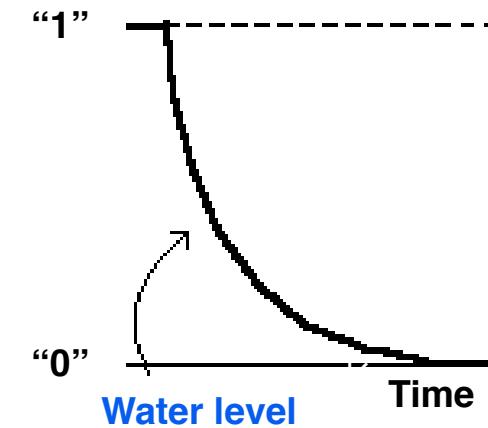
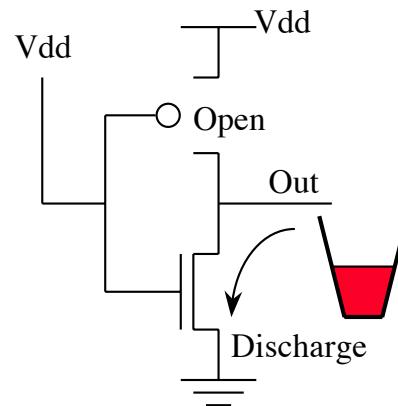
Transistors as water valves. (Cartoon physics)

If electrons are water molecules,
transistor strengths (W/L) are pipe diameters,
and capacitors are buckets ...

A “on” p-FET fills
up the capacitor
with charge.



A “on” n-FET
empties the bucket.



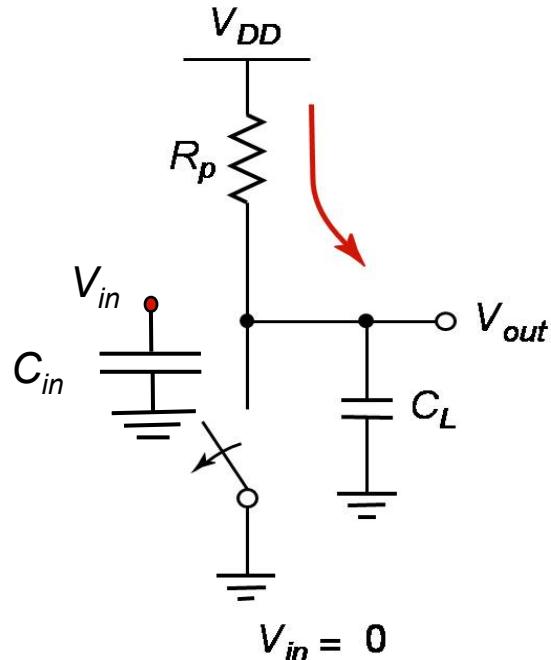
The Switch Inverter: Transient Response

With:

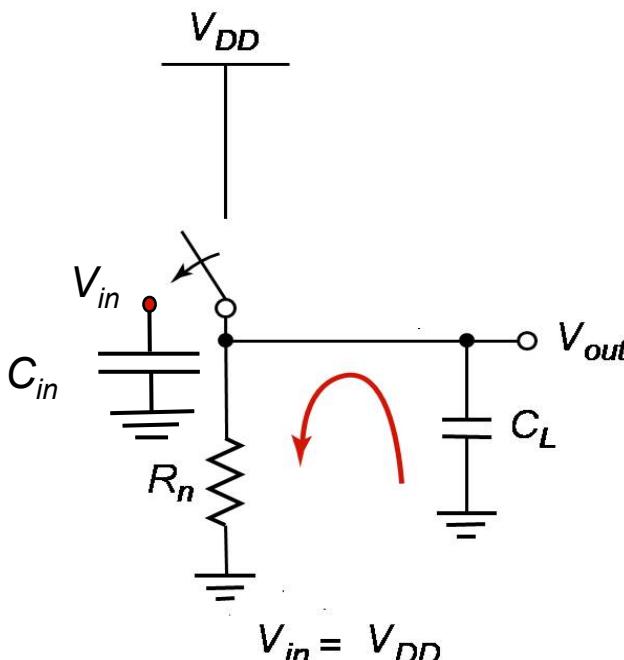
resistive approximation for FETs,
high-to-low (HL)

$$V(t) = V_0 e^{-t/RC}$$

$$t_{1/2} = \ln(2) \times RC$$



(a) Low-to-high

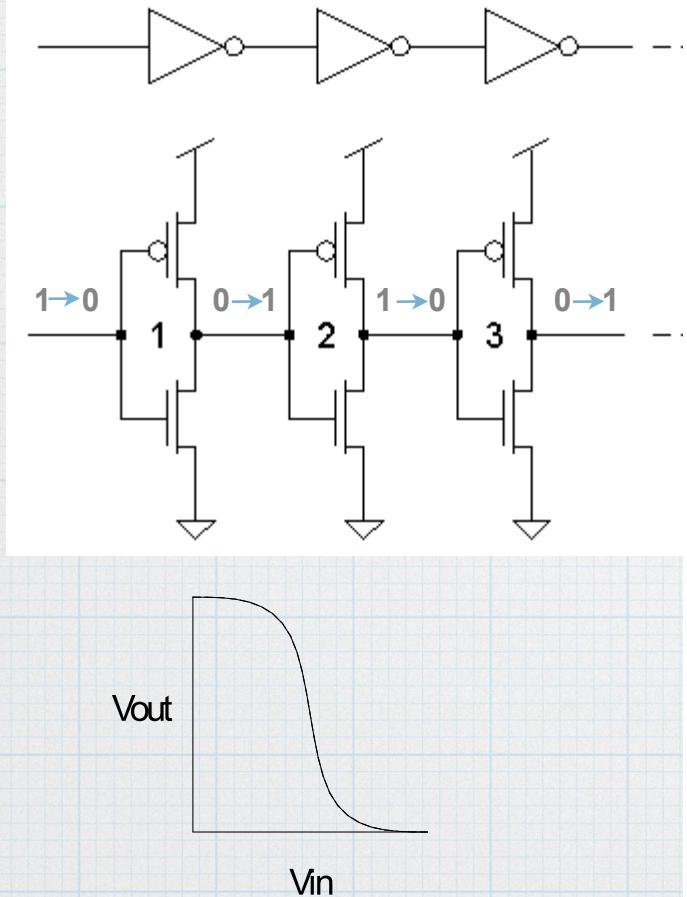


(b) High-to-low

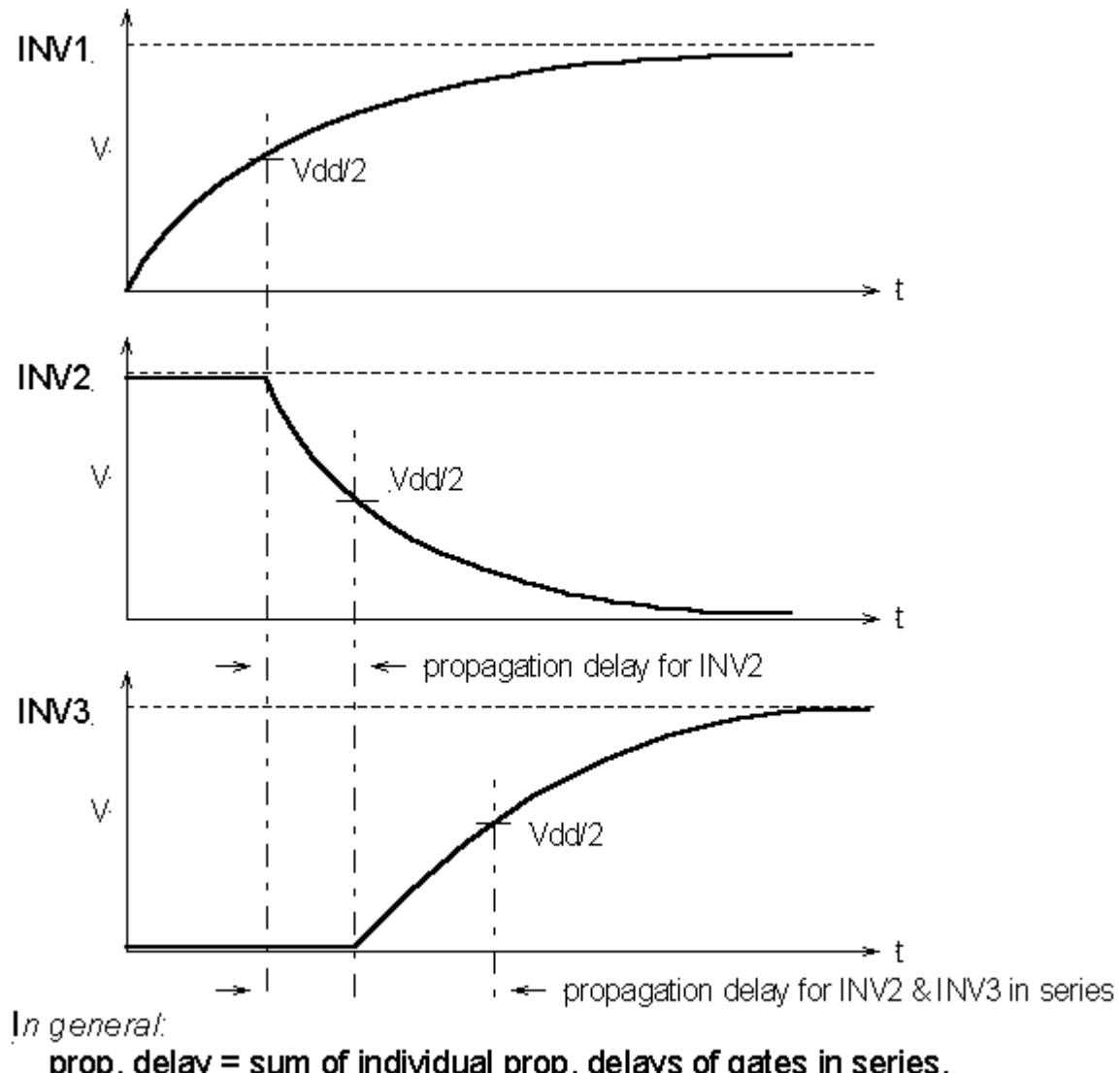
$$\begin{aligned} t_{pHL} &= f(R_{on} C_L) \\ &= 0.69 R_n C_L \end{aligned}$$

Turning Rise/Fall Delay into Gate Delay

- Cascaded gates:

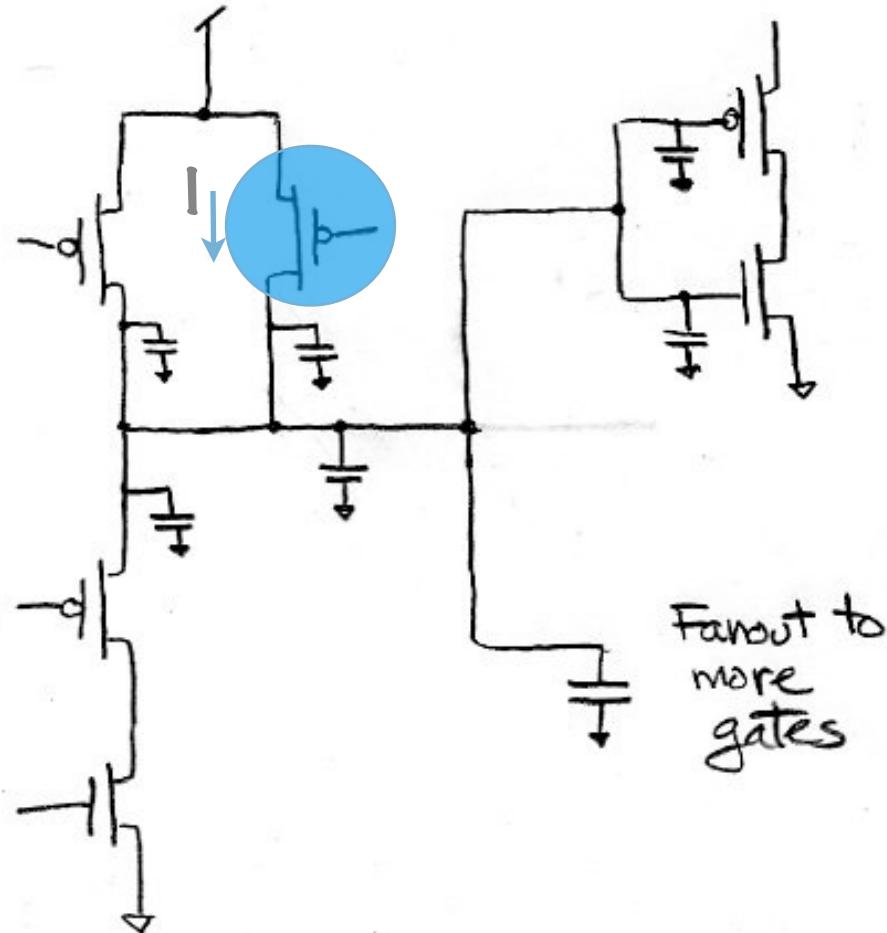


“transfer curve” for inverter.



More on gate delay

- ▶ Everything that connects to the output of a logic gate (or transistor) contributes capacitance:

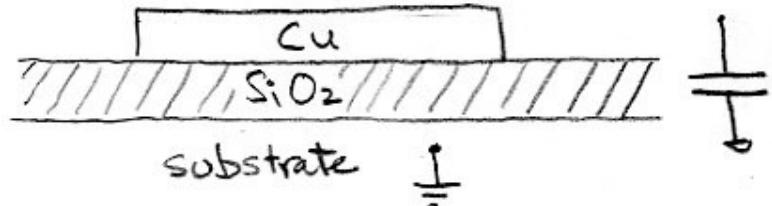


- ▶ Transistor drains
- ▶ Interconnection (wires/contacts/vias)
- ▶ Transistor Gates

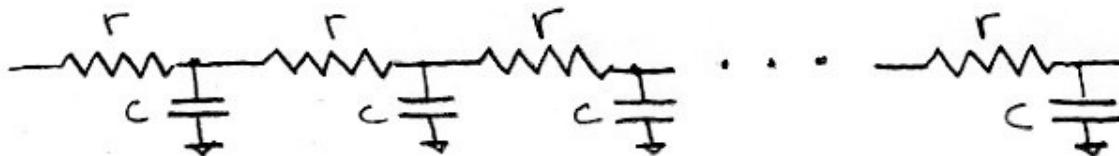
Wires

- As parallel plate capacitors:

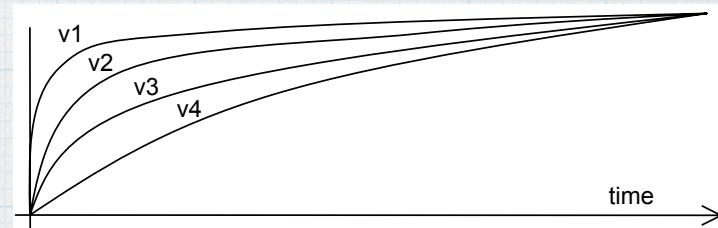
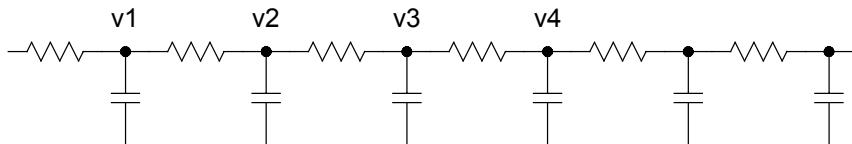
$$C \propto \text{Area} = \text{width} * \text{length}$$



- Wires have some finite resistance, so have distributed R and C:

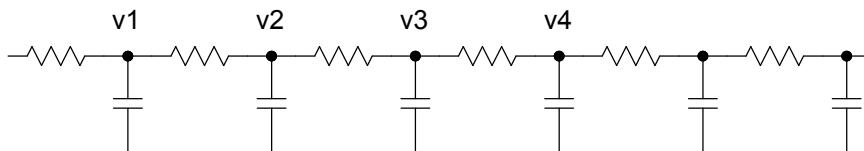


with $r = \text{res/length}$, $c = \text{cap/length}$, $\Delta t \propto rcl^2 \approx rc + 2rc + 3rc + \dots$

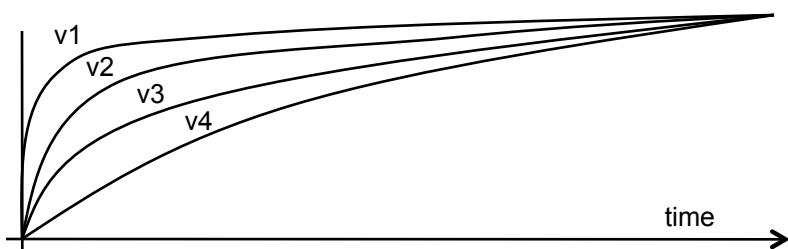


Wire Delay

- Wires possess distributed resistance and capacitance
- *Time constant associated with distributed RC is proportional to the square of the length*

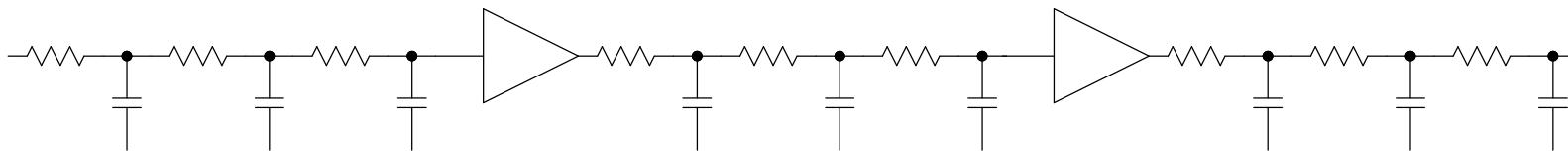


- For **short wires** on ICs, resistance is insignificant (relative to effective R of transistors), but C is important.
 - Typically around half of C of gate load is in the wires.
- For **long wires** on ICs:
 - busses, clock lines, global control signal, etc.
 - Resistance is significant, therefore distributed RC effect dominates.
 - signals are typically “rebuffed” to reduce delay
- For **long wires** on ICs with high currents:
 - *inductance* is also important



Wire Rebuffering

- For **long wires** on ICs:
 - busses, clock lines, global control signal, etc.
 - Resistance is significant, therefore rCL^2 effect dominates.
 - signals are typically “rebuffed” to reduce delay:



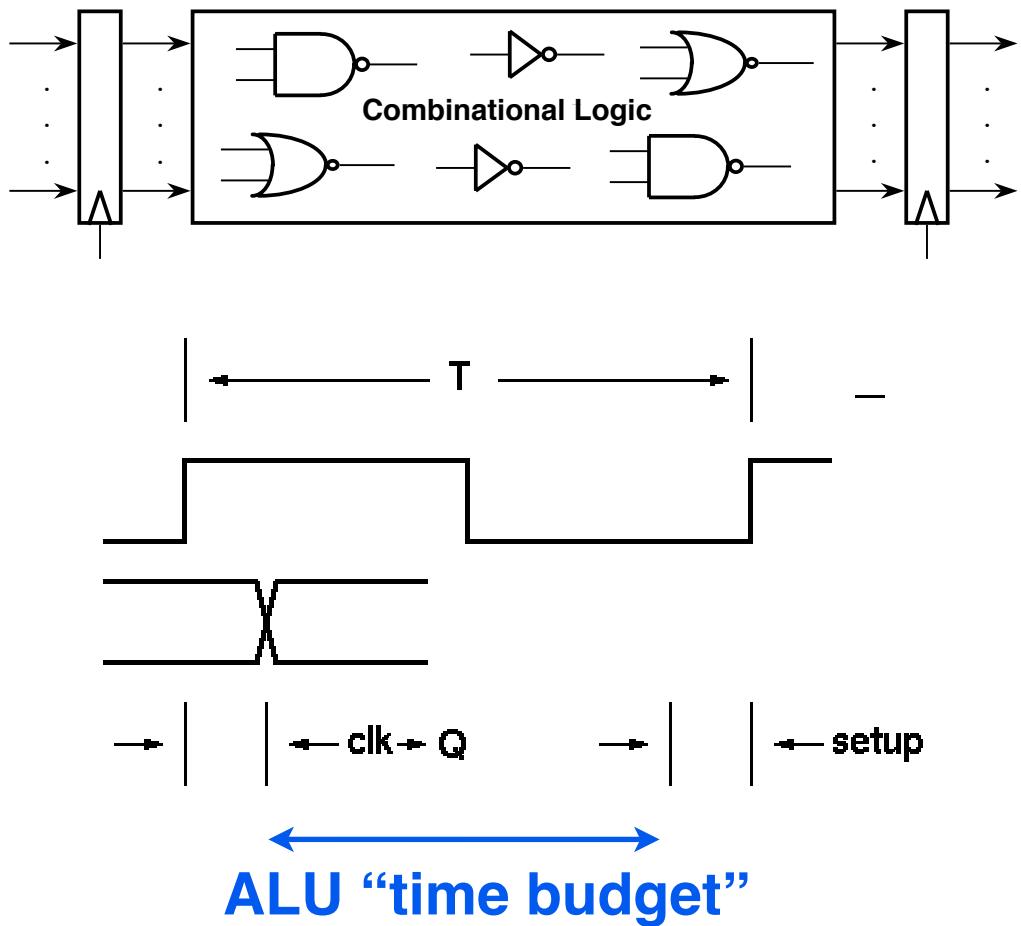
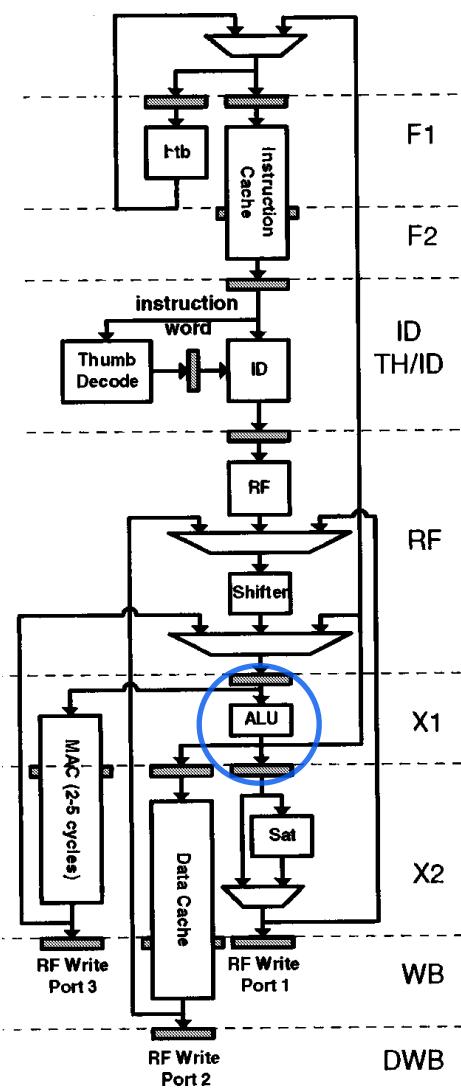
unbuffered wire $\Delta t \propto L^2$

wire buffered into N sections $\Delta t \propto N * (L/N)^2 + (N-1) * t_{buffer}$

Assuming t_{buffer} is small, $\Delta t \propto L^2/N$

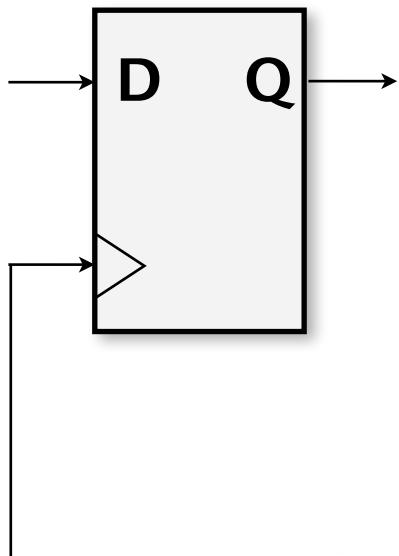
Speedup: $\propto N$

Flip-Flop delays eat into “time budget”

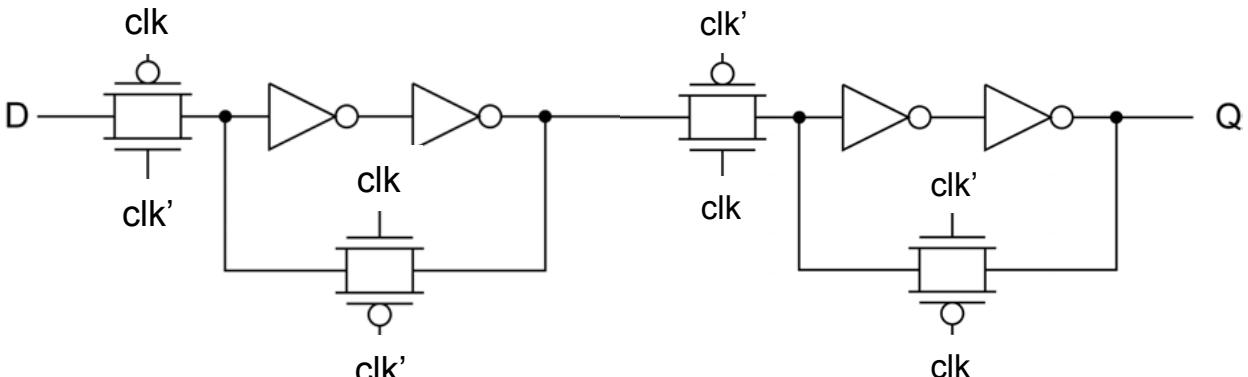


$$T \geq \tau_{\text{clk} \rightarrow \text{Q}} + \tau_{\text{CL}} + \tau_{\text{setup}}$$

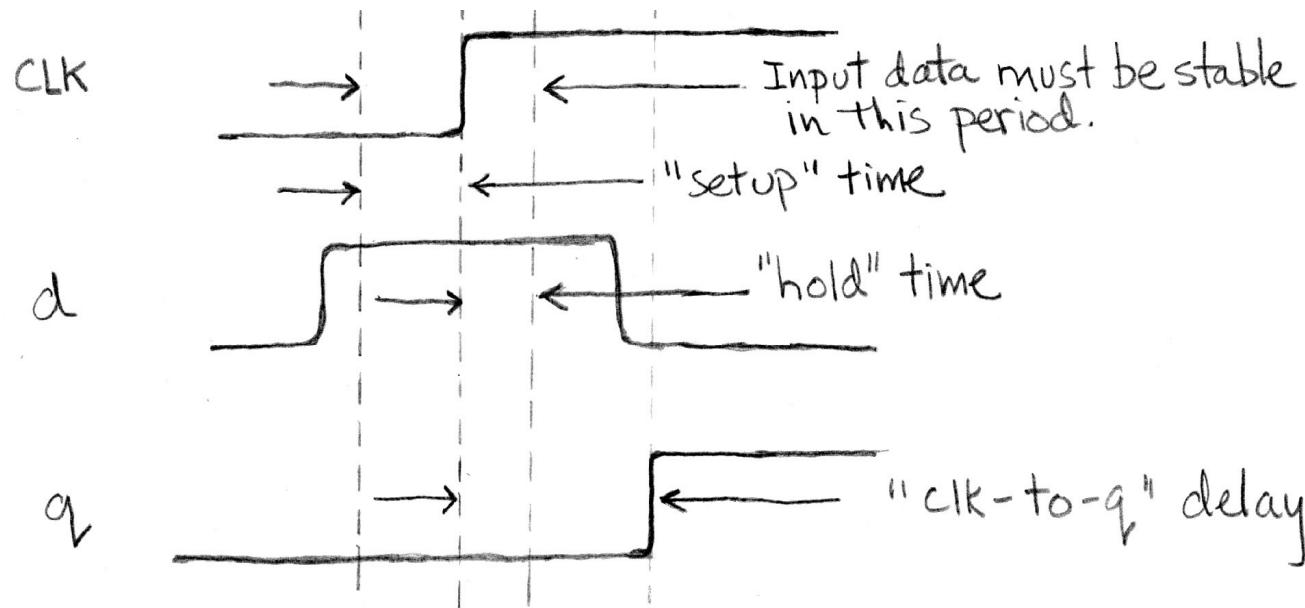
Recall: Positive edge-triggered flip-flop



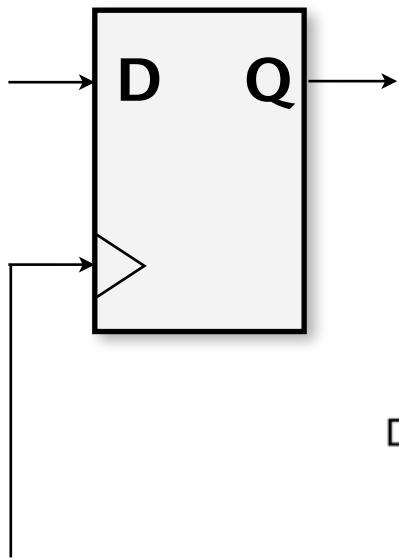
Sampling circuit



Holds value

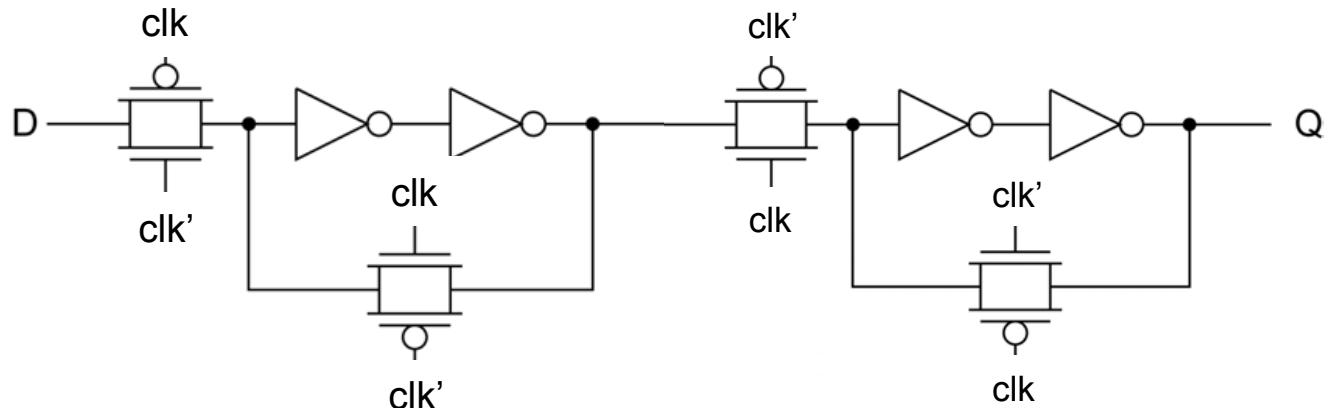


Sensing: When clock is low



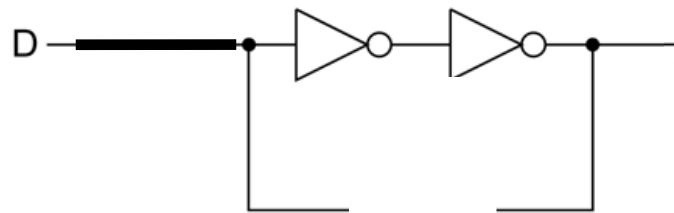
A flip-flop “samples” right before the edge, and then “holds” value.

Sampling circuit



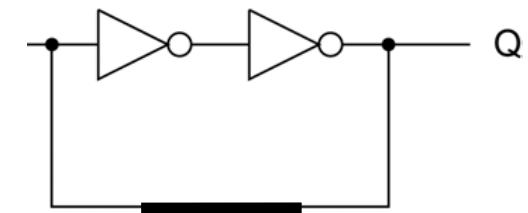
Holds value

$\text{clk} = 0$
 $\text{clk}' = 1$

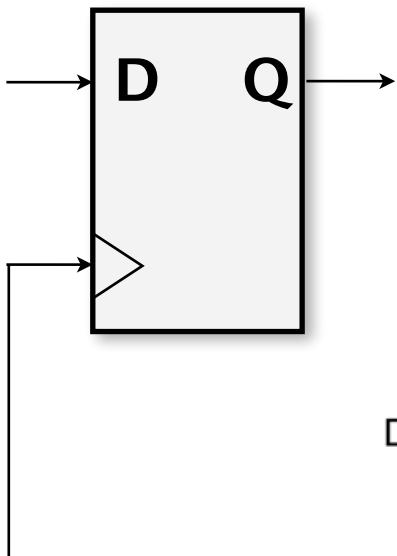


Will capture new value
on posedge.

Outputs last value
captured.

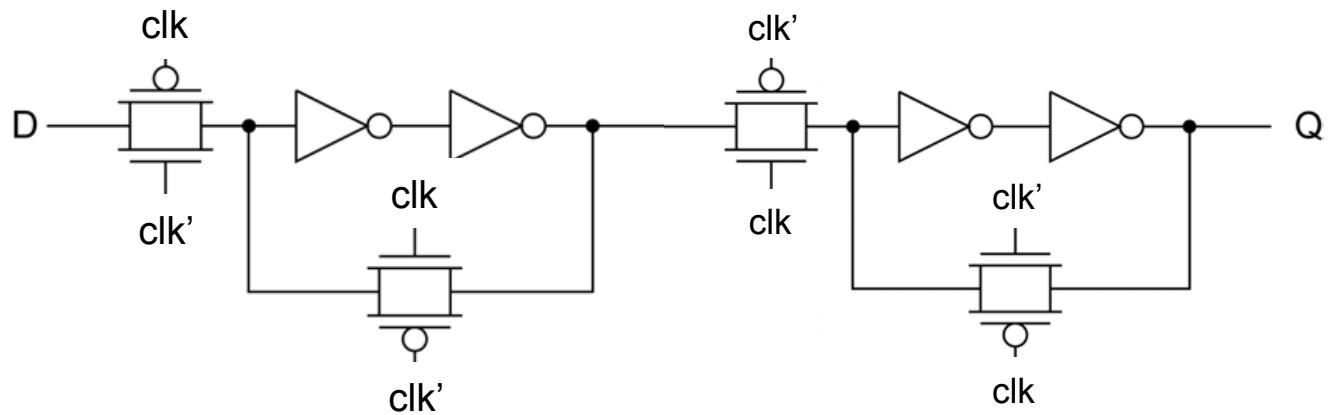


Capture: When clock goes high



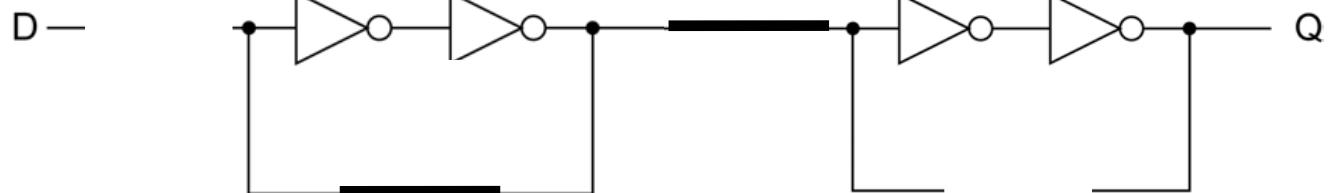
A flip-flop “samples” right before the edge, and then “holds” value.

Sampling circuit



Holds value

$\text{clk} = 1$
 $\text{clk}' = 0$

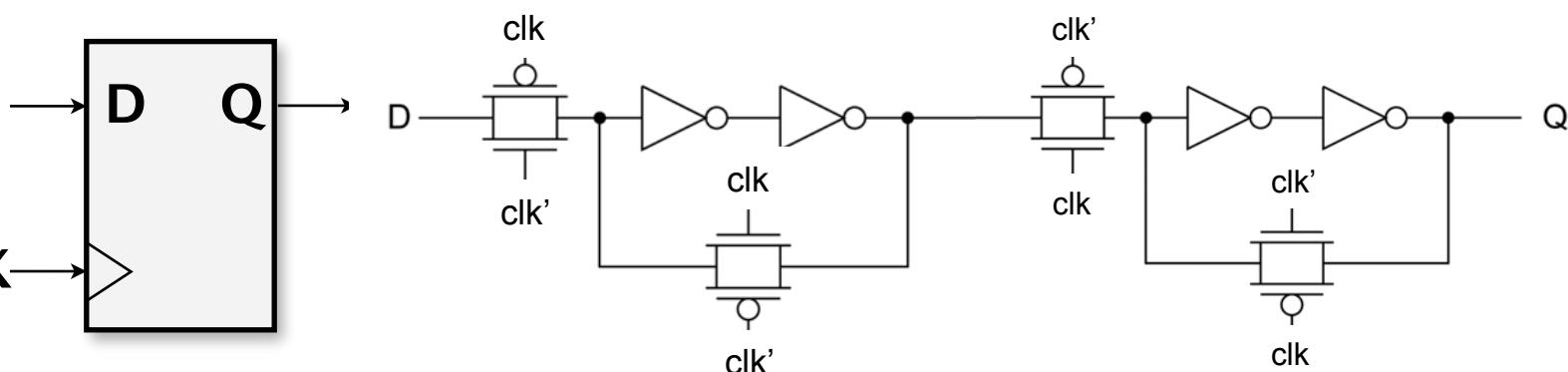


Remembers value
just captured.

Outputs value just
captured.

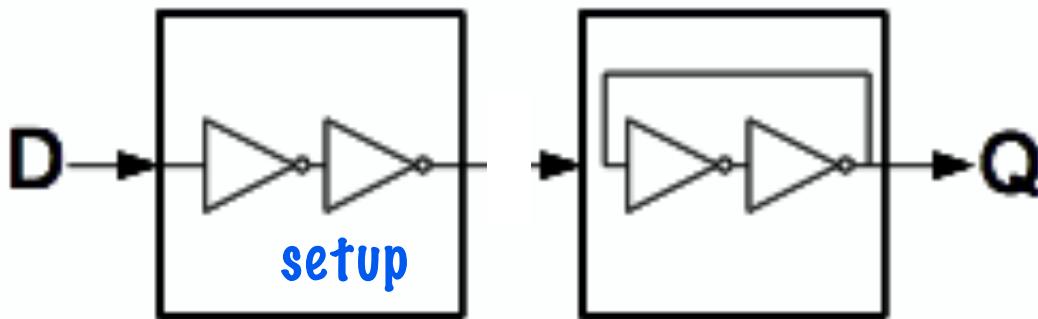
Flip Flop delays:

clk-to-Q ? setup ?



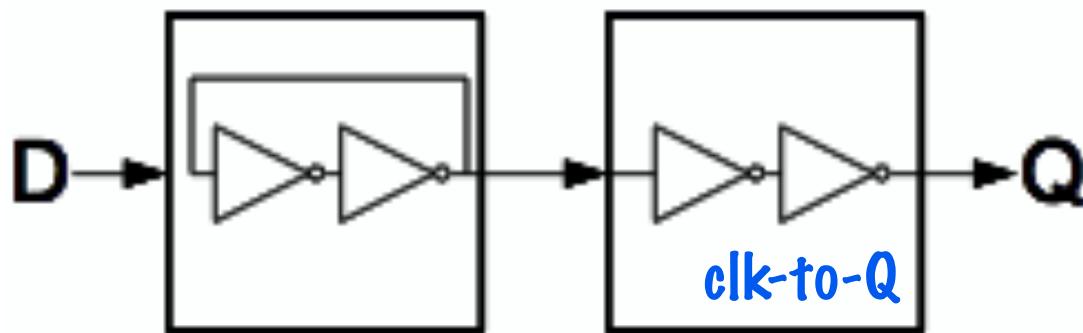
CLK == 0

Sense D, but Q
outputs old value.



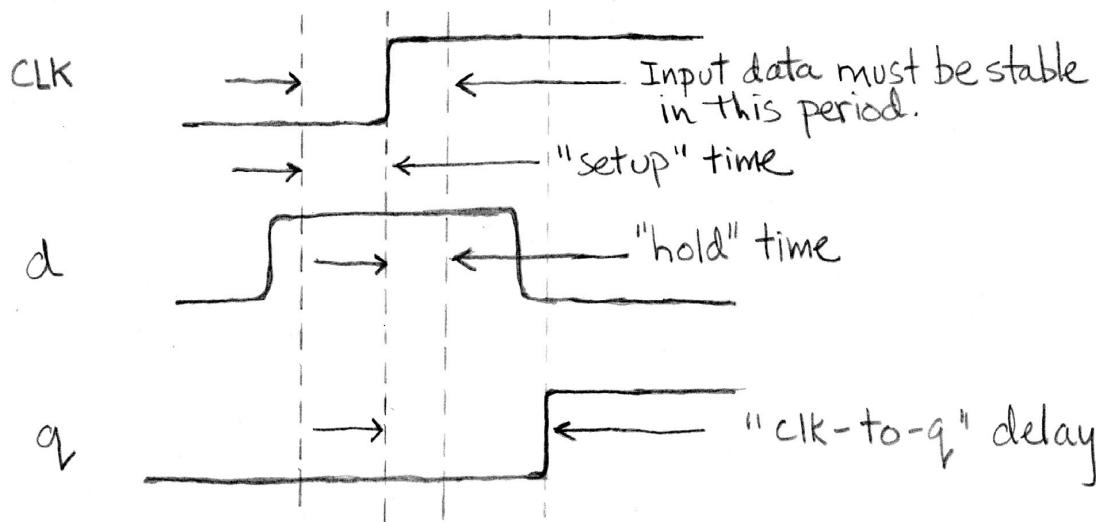
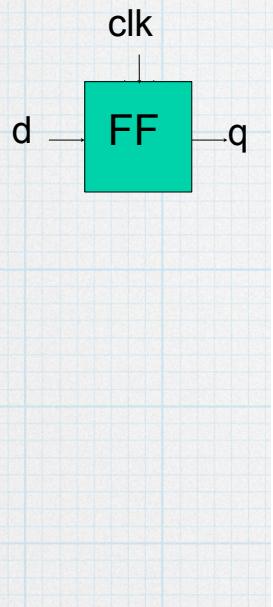
CLK 0->1

Capture D, pass
value to Q



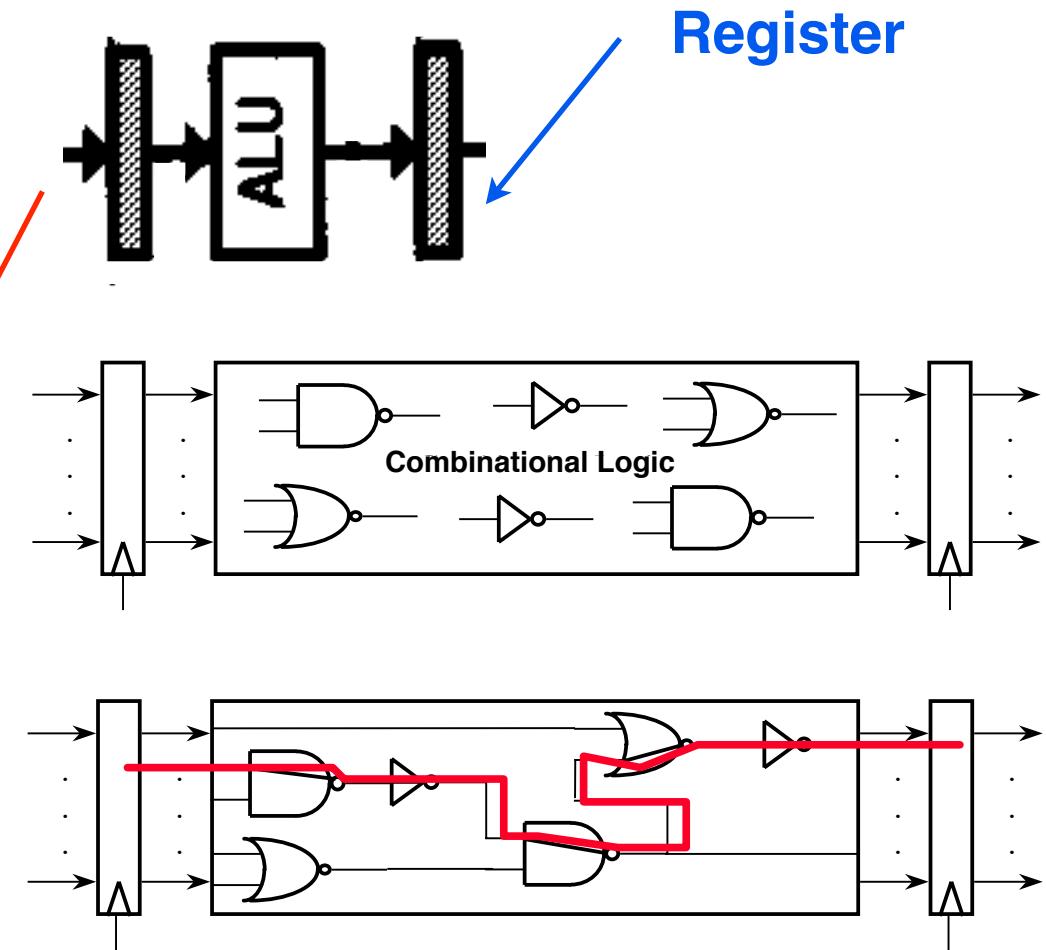
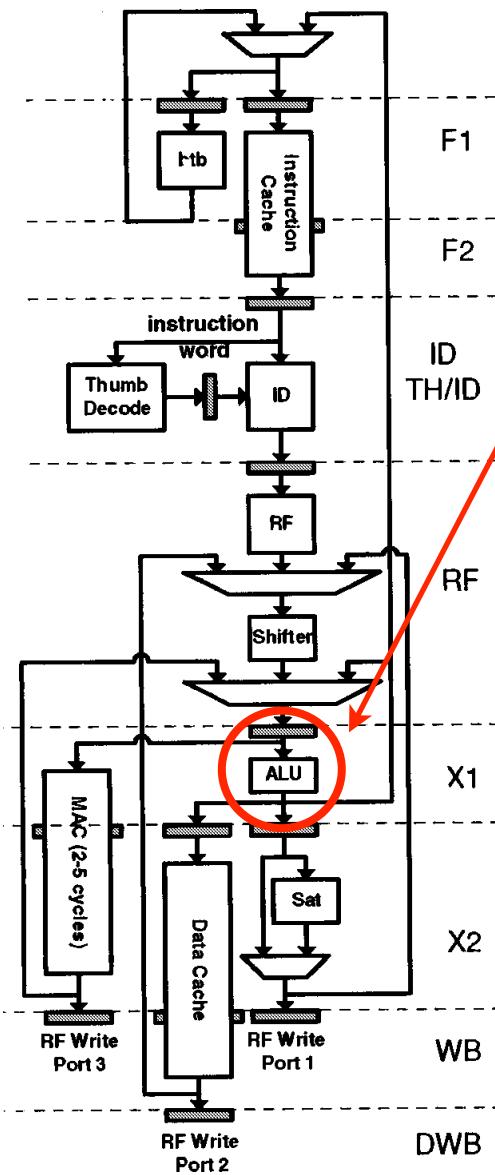
Note: with too much fanout, second stage could fail to capture data properly. Often output is rebuffered.

Hold-time Violations



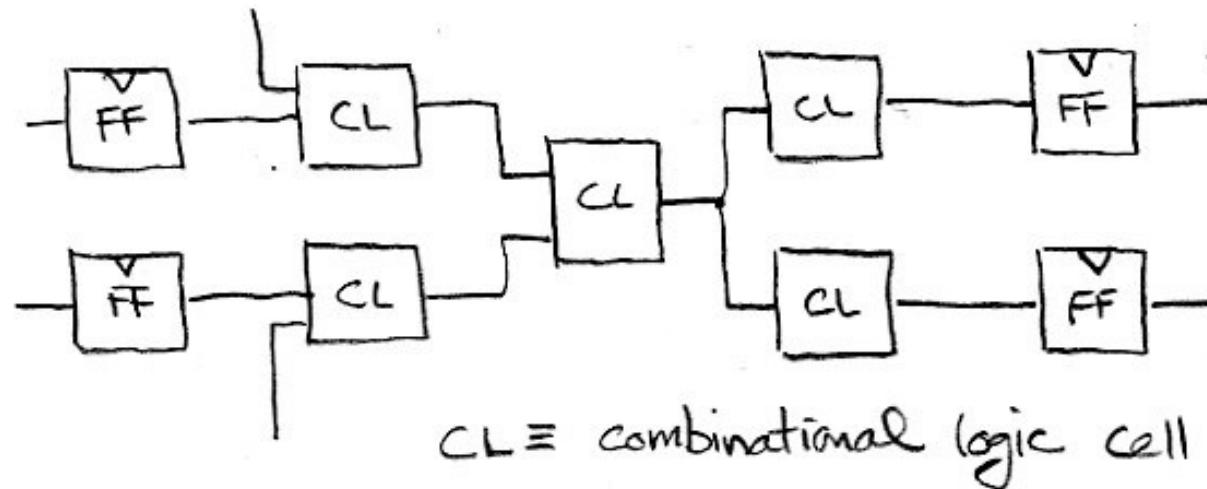
- ▶ Some state elements have positive hold time requirements.
 - ▶ How can this be?
- ▶ Fast paths from one state element to the next can create a violation. (Think about shift registers!)
- ▶ CAD tools do their best to fix violations by inserting delay (buffers).
 - ▶ Of course, if the path is delayed too much, then cycle time suffers.
 - ▶ Difficult because buffer insertion changes layout, which changes path delay.

Timing Analysis and Logic Delay



Some path somewhere in the design has the longest delay and is therefore the "critical path".

Components of Combinational Path Delay

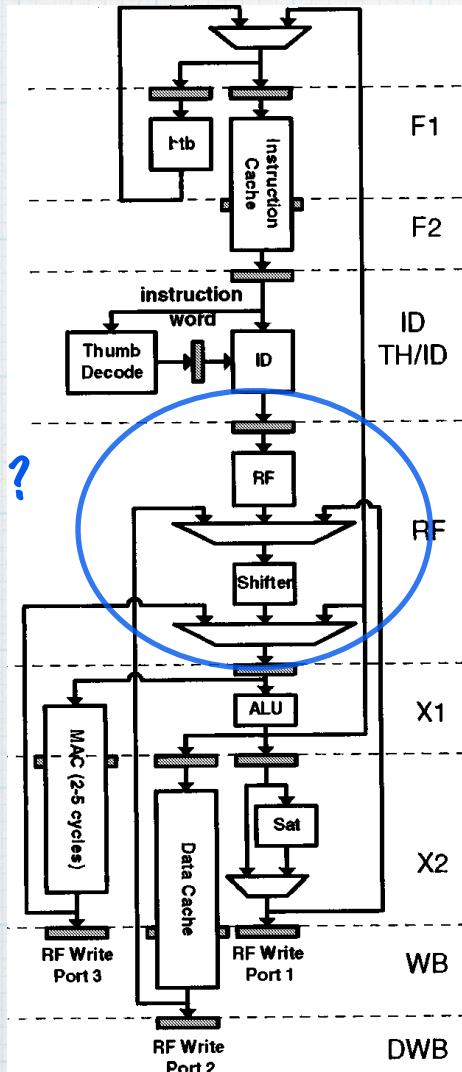


1. # of levels of logic
2. Internal cell delay
3. wire delay
4. cell input capacitance
5. cell fanout
6. cell output drive strength

Who controls the delay in ASIC?

	foundry engineer (TSMC)	Library Developer (Aritsan)	CAD Tools (DC, IC Compiler)	Designer (you!)
1. # of levels			synthesis	HDL design
2. Internal cell delay	physical parameters	cell topology, trans sizing	cell selection	
3. Wire delay	physical parameters		place & route	layout
4. Cell input capacitance	physical parameters	cell topology, trans sizing	cell selection	
5. Cell fanout			synthesis	HDL design
6. Cell drive strength	physical parameters	transistor sizing	cell selection	

Timing Closure: Searching for and beating down the critical path



Must consider all connected register pairs, paths, plus from input to register, plus register to output.

- Design tools help in the search.

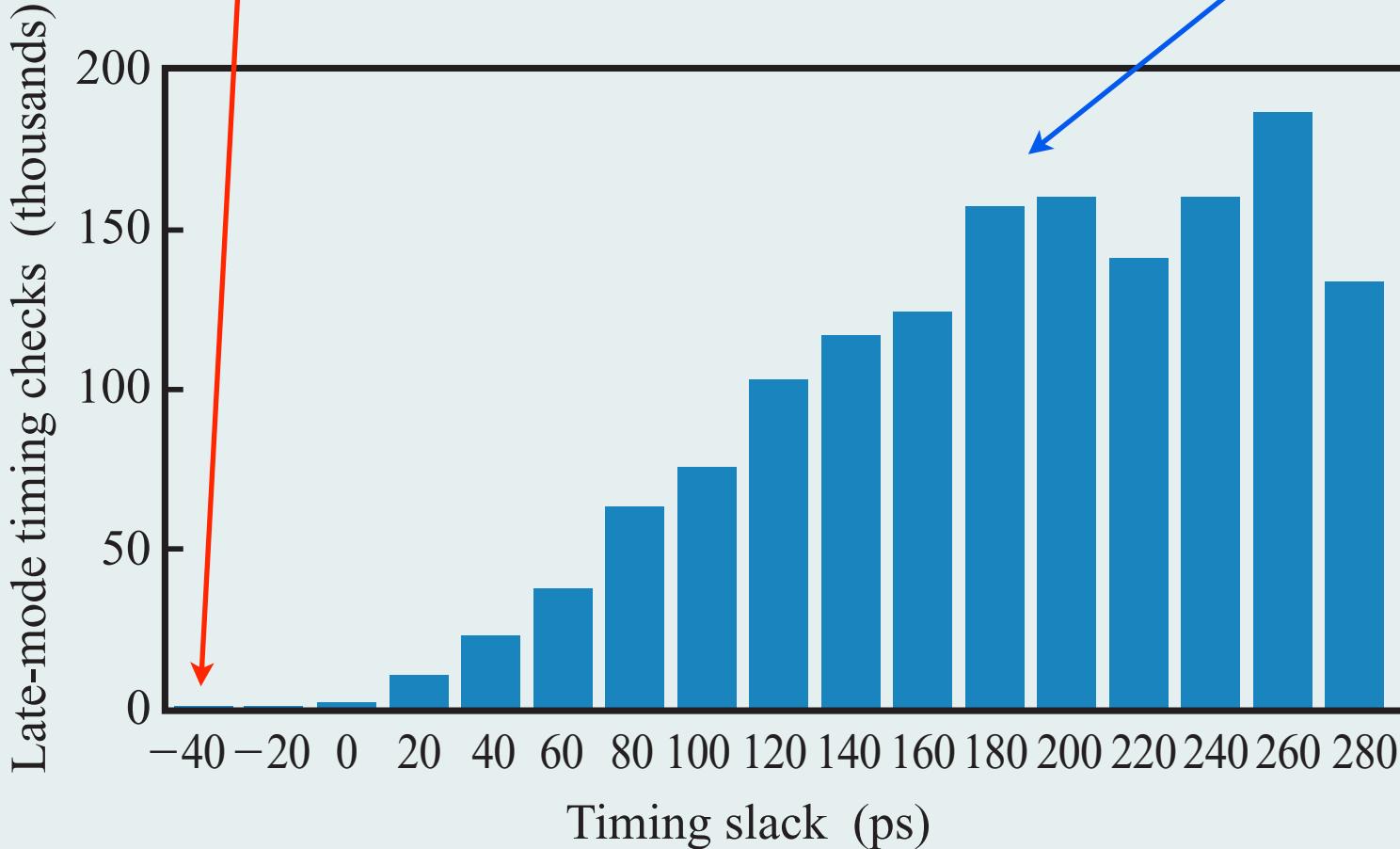
- Synthesis tools work to meet clock constraint, report delays on paths,
- Special static timing analyzers accept a design netlist and report path delays,
- and, of course, simulators can be used to determine timing performance.

Tools that are expected to do something about the timing behavior (such as synthesizers), also include provisions for specifying input arrival times (relative to the clock), and output requirements (set-up times of next stage). 32

Timing Analysis, real example

The critical path

Most paths have hundreds of picoseconds to spare.



From "The circuit and physical design of the POWER4 microprocessor", IBM J Res and Dev, 46:1, Jan 2002, J.D. Warnock et al.

Timing Optimization

As an ASIC/FPGA designer you get to choose:

- ▶ The algorithm
- ▶ The Microarchitecture (block diagram)
- ▶ The HDL description of the CL blocks
(number of levels of logic)
- ▶ Where to place registers and memory (the pipelining)
- ▶ Overall floorplan and relative placement of blocks

Circuit retiming

Critical path is 5
(ignore FF delay for now).

We want to improve it without changing circuit semantics.

Add a register, move one circle.
Performance improves by 20%.

Circles are combinational logic, labelled with delays.

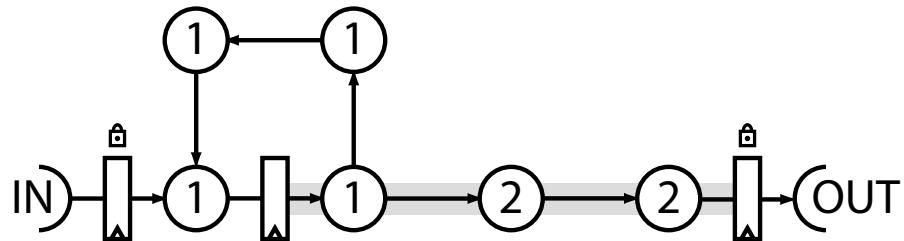


Figure 1: A small graph before retiming. The nodes represent logic delays, with the inputs and outputs passing through mandatory, fixed registers. The critical path is 5.

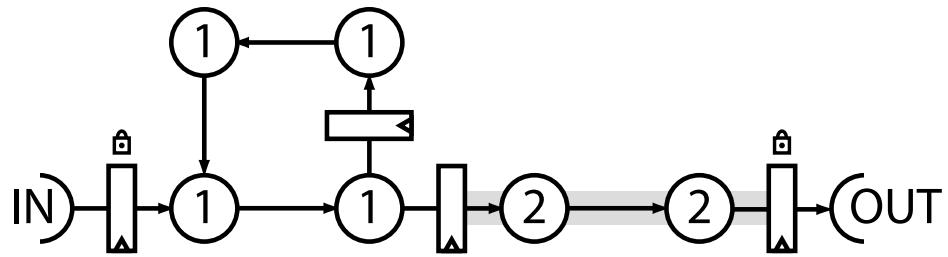
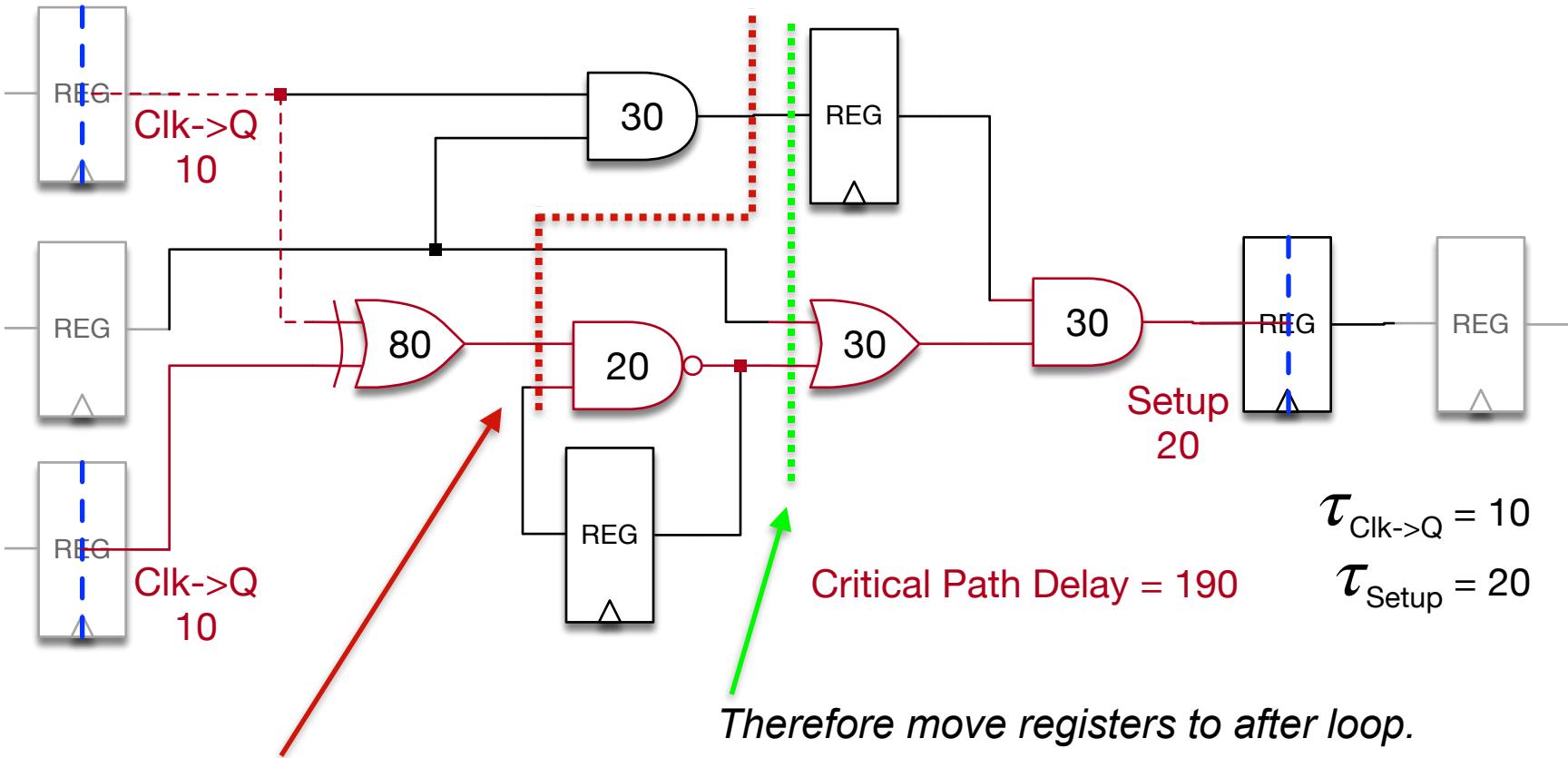


Figure 2: The example in Figure 2 after retiming. The critical path is reduced from 5 to 4.

Logic Synthesis tools can do this in simple cases.

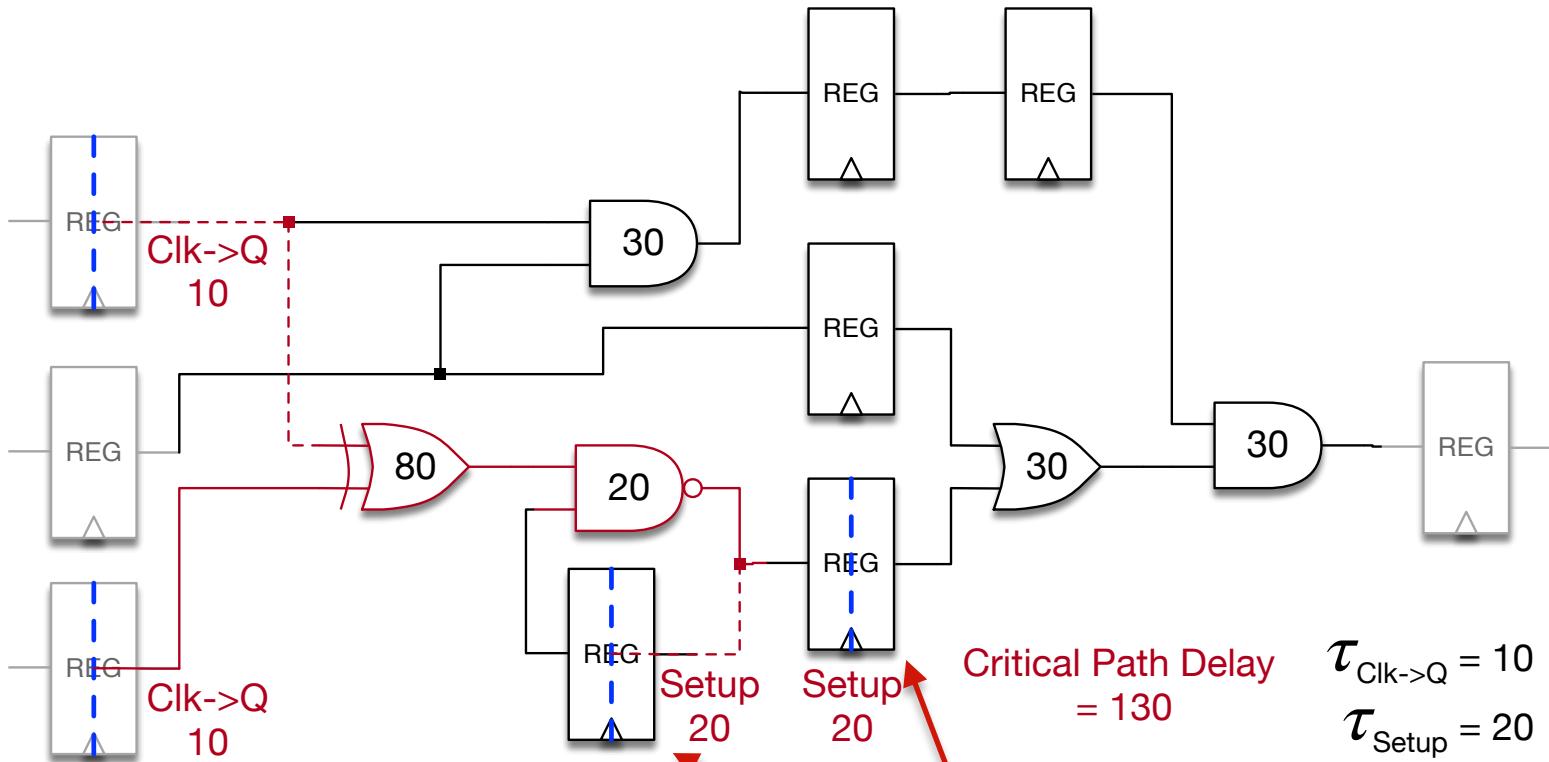
Retiming Example



Want to retime to here, however,
delay cannot be added to the loop
without changing the semantics of
the logic. Because of this, many
retiming tools stop at loops.

Therefore move registers to after loop.

Retiming Example

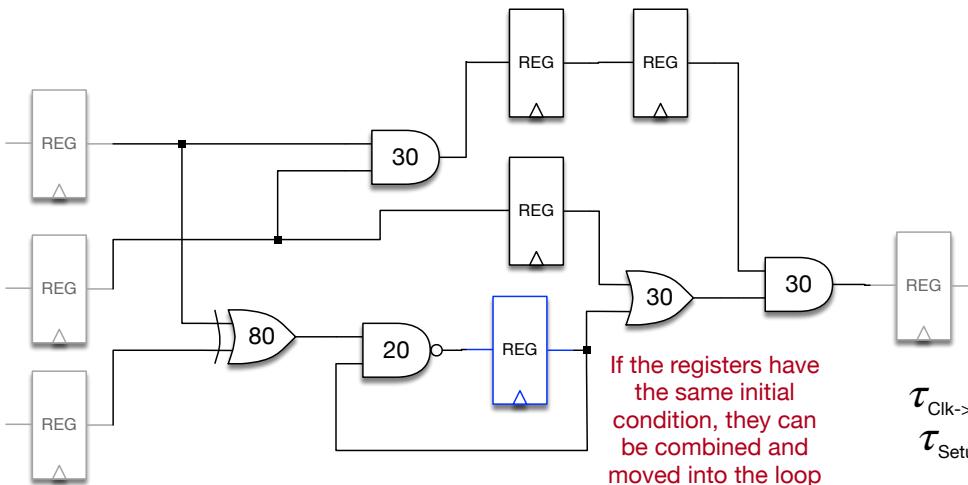


This is the retimed solution that many retiming aware tools will stop at.

This is also the optimal solution when the initial values of the registers are not given.

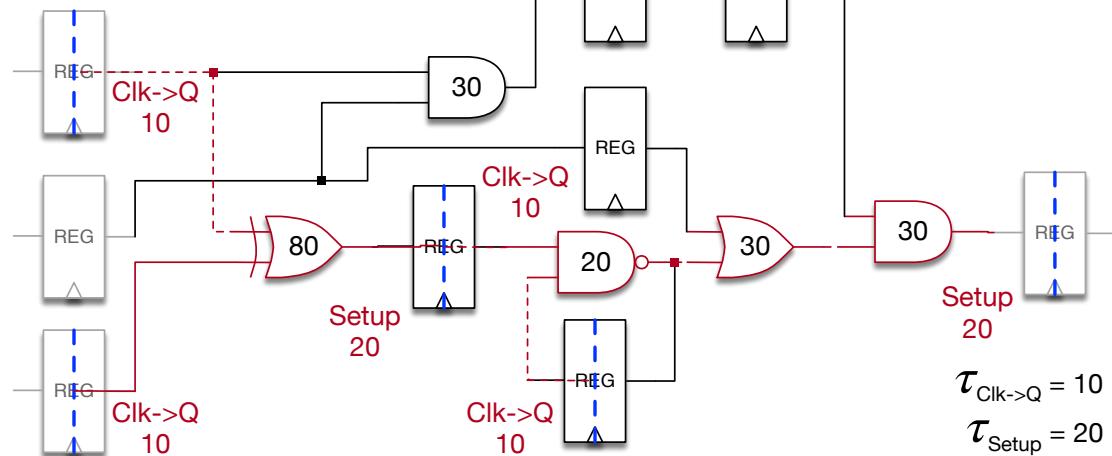
If the registers have the same initial condition, they can be combined and moved into the loop

Retiming Example



If the registers have the same initial condition, they can be combined and moved into the loop

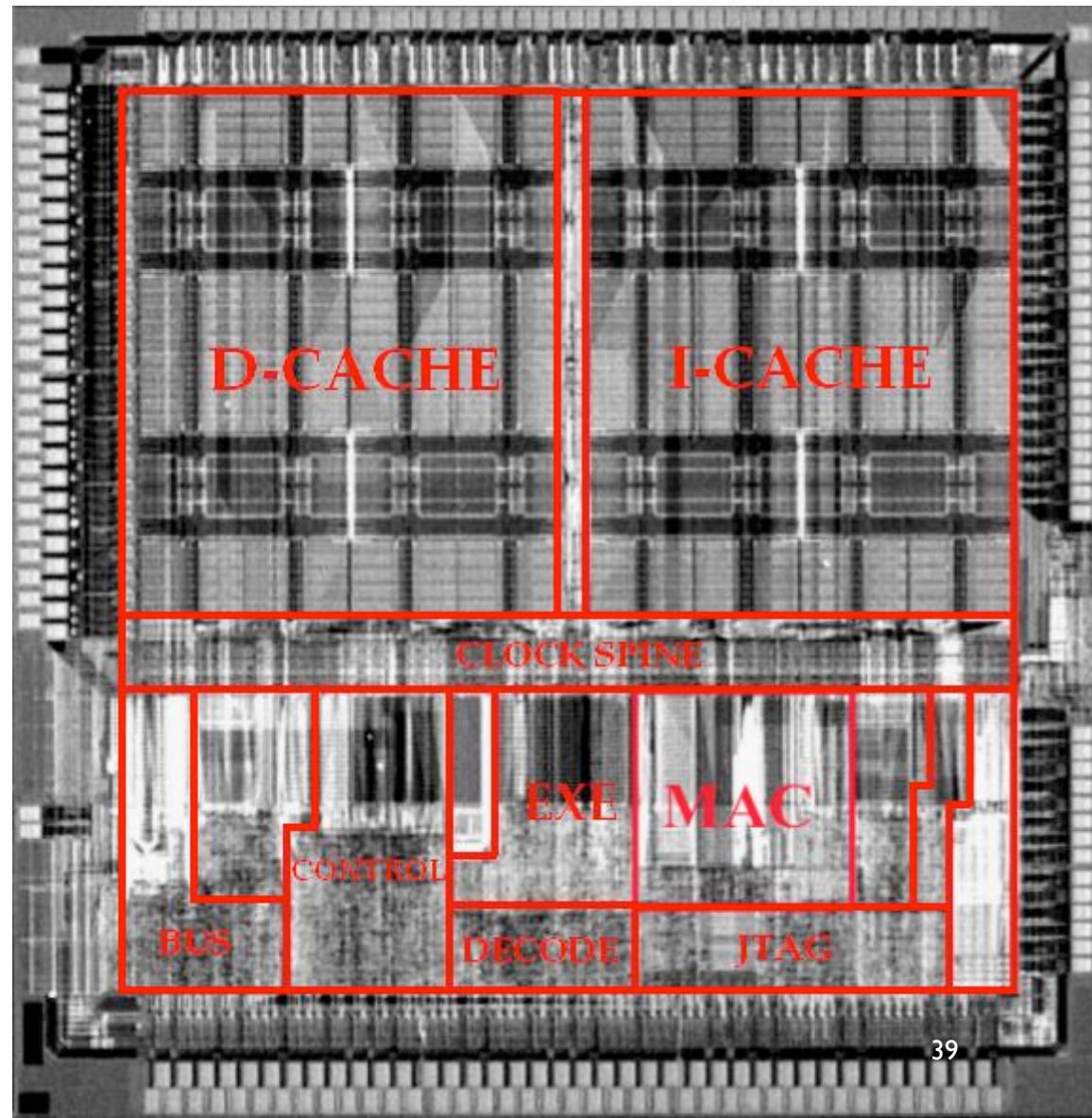
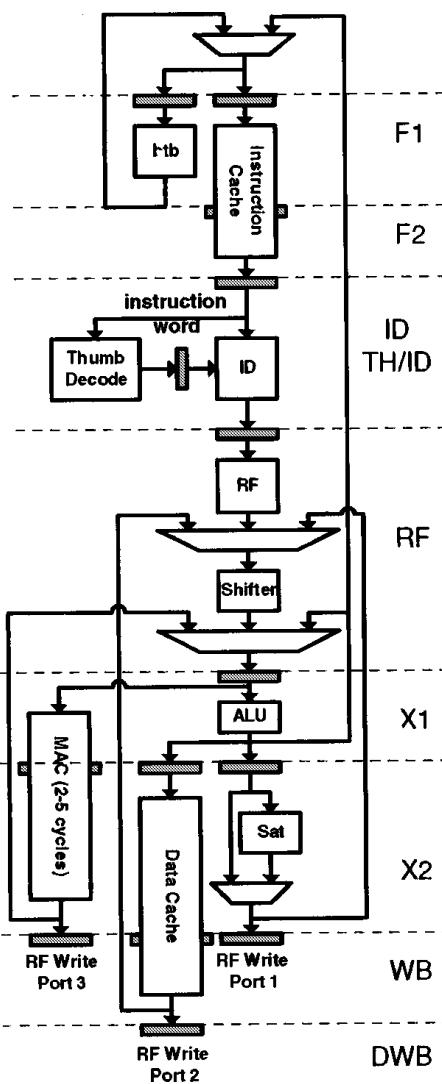
$$\begin{aligned}\tau_{\text{Clk} \rightarrow Q} &= 10 \\ \tau_{\text{Setup}} &= 20\end{aligned}$$



The register can be moved through the NAND gate, producing a register at each input. The total delay in the loop is unchanged. Care must be taken to properly set the initial conditions of the registers.

$$\begin{aligned}\text{Critical Path Delay} &= 110 \\ \tau_{\text{Clk} \rightarrow Q} &= 10 \\ \tau_{\text{Setup}} &= 20\end{aligned}$$

Floorplaning: essential to meet timing.



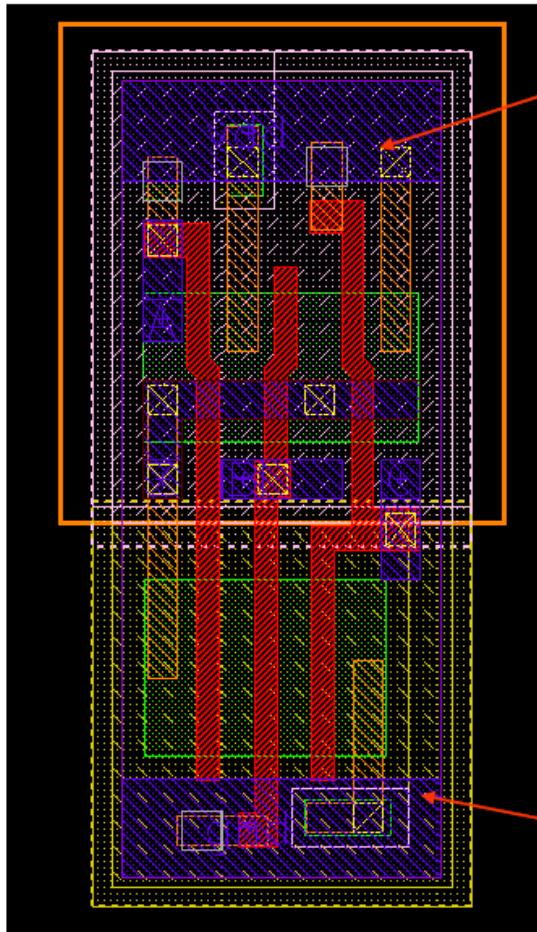
(Intel XScale 80200)

Timing Analysis Tools

- ▶ Static Timing Analysis: Tools use delay models for gates and interconnect. Traces through circuit paths.
 - ▶ Cell delay model capture
 - ▶ For each input/output pair, internal delay (output load independent)
 - ▶ output dependent delay
- ▶ Standalone tools (PrimeTime) and part of logic synthesis.
- ▶ Back-annotation takes information from results of place and route to improve accuracy of timing analysis.
- ▶ DC in “topographical mode” uses preliminary layout information to model interconnect parasitics.
 - ▶ Prior versions used a simple fan-out model of gate loading.



Standard cell characterization



Power Supply Line (V_{DD}) Delay in (ns)!!

Path	1.2V - 125°C	1.6V - 40°C
$In1-t_{pLH}$	$0.073+7.98C+0.317T$	$0.020+2.73C+0.253T$
$In1-t_{pHL}$	$0.069+8.43C+0.364T$	$0.018+2.14C+0.292T$
$In2-t_{pLH}$	$0.101+7.97C+0.318T$	$0.026+2.38C+0.255T$
$In2-t_{pHL}$	$0.097+8.42C+0.325T$	$0.023+2.14C+0.269T$
$In3-t_{pLH}$	$0.120+8.00C+0.318T$	$0.031+2.37C+0.258T$
$In3-t_{pHL}$	$0.110+8.41C+0.280T$	$0.027+2.15C+0.223T$

3-input NAND cell
(from ST Microelectronics):
C = Load capacitance
T = input rise/fall time

Ground Supply Line (GND)

- Each library cell (FF, NAND, NOR, INV, etc.) and the variations on size (strength of the gate) is fully characterized across temperature, loading, etc.

End of Lecture 11